Diode Semiconductor Device - Page 1 of 1



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## **Inclosure Material:** Ceramic and glass **Overall Length:** Between 0.264 inches and 0.274 inches **Overall Diameter:** 0.125 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes forward current, average horsepower metric **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector absolute Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0